

FEATURES

- Hyperfast recovery time, reduced Q_{rr} and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM/CCM, snubber operation
- Low forward voltage drop
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V _{RRM}		600	V			
Average rectified forward current	I _{F(AV)}	$T_{L} = 76 \ ^{\circ}C \ ^{(1)}$	4	А			
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \ ^{\circ}C$, 6 ms square pulse	55	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

Note

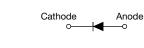
⁽¹⁾ Mounted on PCB with minimum pad size

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage	VF	$I_F = 4 A$	-	1.6	1.95	V	
r of ward voltage	۷F	I _F = 4 A, T _J = 150 °C	-	1.2	1.4		
Reverse leakage current I _R		$V_{R} = V_{R}$ rated	-	-	3		
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	100	μA	
Junction capacitance	CT	V _R = 600 V	-	5.7	-	pF	

 Revision: 03-Sep-2019
 1
 Document Number: 94775

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT
ARE SUBJECT TO SPECIFI
 Downloaded From Oneyac.com
 w.vishay.com/doc?91000





SMB (DO-214AA)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	4 A				
V _R	600 V				
V _F at I _F	1.2 V				
t _{rr} typ.	30 ns				
T _J max.	175 °C				
Package	SMB (DO-214AA)				
Circuit configuration	Single				

VISHAY. www.vishay.com

(e3

RoHS

COMPLIANT HALOGEN

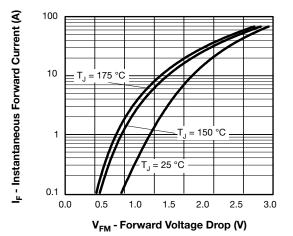


DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		-	30	-		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50$	0 Α/μs, V _R = 30 V	-	35	-		
Reverse recovery time	t _{rr}	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_r$	= 0.5 A, I _R = 1 A, I _{rr} = 0.25 A			35	ns	
		T _J = 25 °C		-	22	-		
		T _J = 125 °C		-	37	-		
Pools receivers ourrent	I _{RRM}	T _J = 25 °C	$I_F = 4 A$	-	3.4	-	А	
Peak recovery current		T _J = 125 °C	dI _F /dt = 200 A/µs V _R = 390 V	-	5.2	-	A .	
	0	T _J = 25 °C		-	40	-	nC	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	103	-	nc	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to case	R _{thJC} ⁽¹⁾		-	-	18	°C/W
Thermal resistance, junction to ambient	R _{thJA} ⁽¹⁾		-	-	90	0/10
Approvimete Weight				0.1		g
Approximate Weight			0.003			oz.
Marking device		Case style SMB (DO-214AA)		41	-16	•

Note

⁽¹⁾ Mounted on PCB with minimum pad size





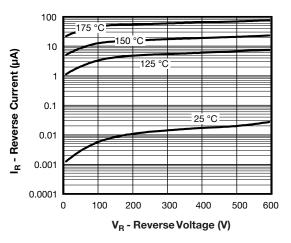
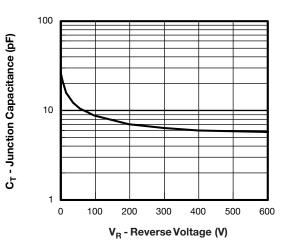


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage





www.vishay.com

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

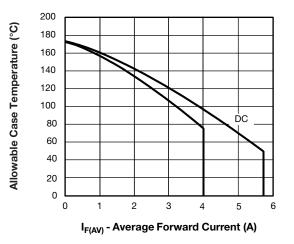
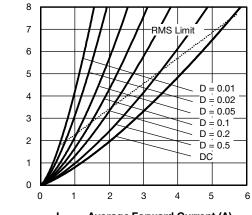


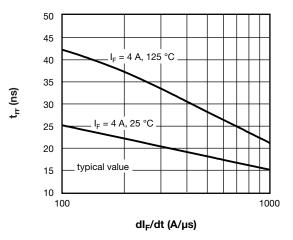
Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

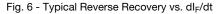


Average Power Loss (W)

I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Forward Power Loss Characteristics





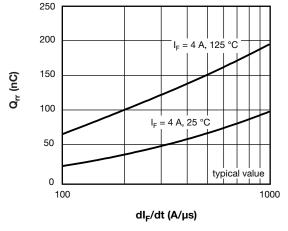


Fig. 7 - Typical Stored Charge vs. dl_F/dt



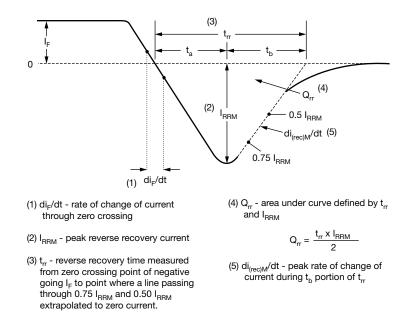


Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

www.vishay.com

					1		
Device code	VS-	4	E	G	н	06	-M3
		<u> </u>					
		(2)	(3)	(4)	(5)	(6)	
	\bigcirc	(2)	\bigcirc	4	\bigcirc	\bigcirc	()
	1	- Vis	hav Sen	nicondu	ctors pro	oduct	
	브					50001	
	2 -	- Cur	rent rati	ng (4 =	4 A)		
	3.	- Circ	cuit conf	iguratio	n:		
		E =	single o	liode			
	4	- G =	SMB p	ackage			
	5.	- Pro	cess typ	e,			
		Н=	hyperfa	st recov	/erv		
			51		5		
	6	- voi	age coo	le (06 =	600 V)		
	7.	- M3	= halog	en-free,	RoHS-	complia	nt, and

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-4EGH06-M3/5BT	5BT	3200	13"diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95401						
Part marking information	www.vishay.com/doc?95472					
Packaging information www.vishay.com/doc?95404						

Revision: 03-Sep-2019

Document Number: 94775

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From <u>Oneyac.com</u> <u>w.vishay.com/doc?91000</u>

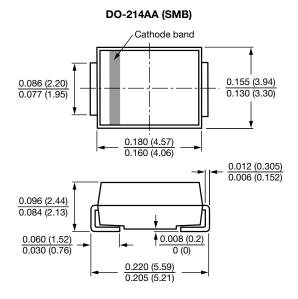


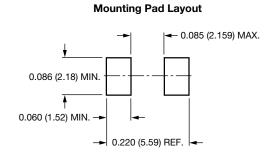
Outline Dimensions

Vishay Semiconductors

SMB

DIMENSIONS in inches (millimeters)







Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.



单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)

>>点击查看相关商品